

DESCRIPTION

The fundamental of SP6014 synchronous rectifier (SR) driver IC is based on our U.S. patented methods that utilize the principle of "prediction" logic circuit. The IC deliberates previous cycle timing to linear control the SR in present cycle by "predictive" algorithm that makes adjustments to the turn-off time, in order to achieve maximum efficiency and avoid cross-conduction at the same time. Specially, SP6014 is designed for LLC applications, and variable switching frequency system.

APPLICATIONS

- Switching Mode Power Supply (CCM&DCM&QR) for Flyback , Forward or LLC Applications
- Storage area network power supplies
- Telecommunication converters
- Embedded systems
- Industrial & commercial systems using high current processors
- Power converters to meet Lot 6 requirement

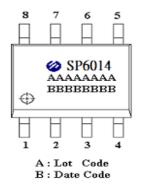
FEATURES

- Offers efficiency improvement over Schottky Diode.
- Low Standby Power to meet DOE Lot 6 Requirement.
- Drives all level Power MOSFET.
- Prediction gate timing control.
- Minimum MOSFET body diode conduction.
- Operating frequency up to 250 KHz.
- Synchronize to transformer secondary voltage waveform.
- Self detect DCM / CCM to enhance the performance under the variable switching frequency condition.

PIN CONFIGURATION (SOP-8)

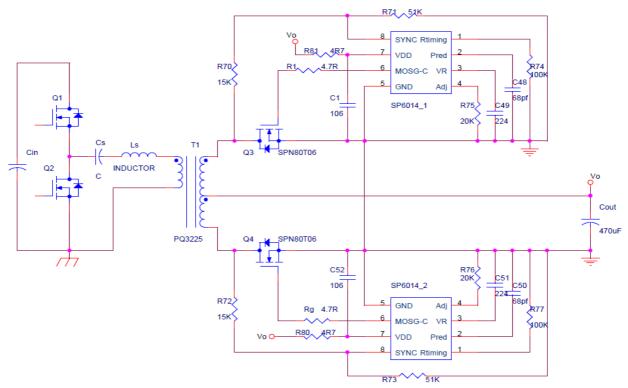


PART MARKING





TYPICAL APPLCATION CIRCUIT

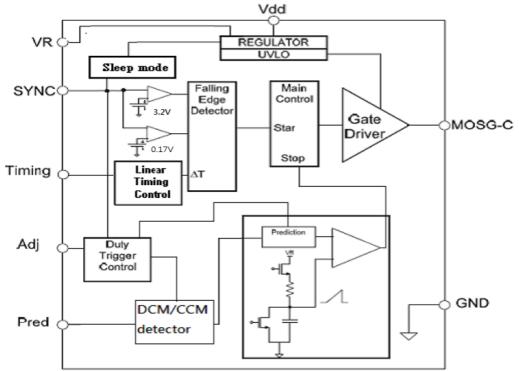


PIN DESCRIPTION

Pin	Symbol	Description		
1	Timing	Discontinuous current filter timing adjustment resistor connection.		
2	Pred	Capacitor to store previous cycle timing for SR MOSFET.		
3	VR	Voltage Regulator.		
4	Adj	Trigger point adjustment for Dynamic state.		
5	GND	Ground connection.		
6	MOSG-C	Catch MOSFET gate drive.		
7	Vdd	DC supply voltage.		
8	SYNC	Synchronized signal from the V _{DS} of SR MOSFET.		

SP6014 Synchronous Rectifier Driver

BLOCK DIAGRAM



ORDERING INFORMATION

Part Number	Package	Part Marking
SP6014S8RGB	SOP-8	SP6014

* SP6014S8RGB : Tape Reel ; Pb – Free ; Halogen - Free

ABSOULTE MAXIMUM RATINGS (TA=25°C, unless otherwise specified.)

The following ratings designate persistent limits beyond which damage to the device may occur.

Symbol	Parameter	Value	Unit
V _{dd}	DC Supply Voltage	16	V
Interview Peak Source Current (Pulsed)	Peak Source Current (Pulsed)	2.0	А
TOUT	Peak Sink Current (Pulsed)	2.0 2.0 0.25 -40 to125	А
P _D	Power Dissipation @ $T_A=85^{\circ}C$ (*)	0.25	W
T _J	Operating Junction Temperature Range	-40 to125	°C
T _{STG}	Storage Temperature Range	-40 to 150	°C
T _{LEAD}	Lead Soldering Temperature for 5 sec.	260	°C

THERMAL RESISTANCE

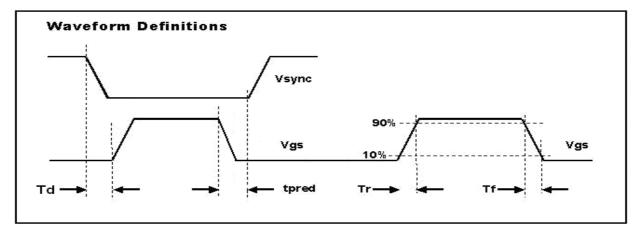
Symbol	Parameter	Value	Unit		
Roja	Thermal Resistance Junction to Ambient (*)	150	°C/W		
(*) The power dissingtion and thermal resistance are evaluated under conner board mounted with free air conditions					

(*) The power dissipation and thermal resistance are evaluated under copper board mounted with free air conditions.

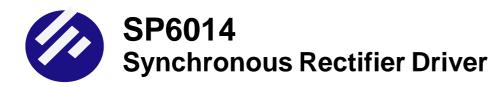


SP6014 **Synchronous Rectifier Driver**

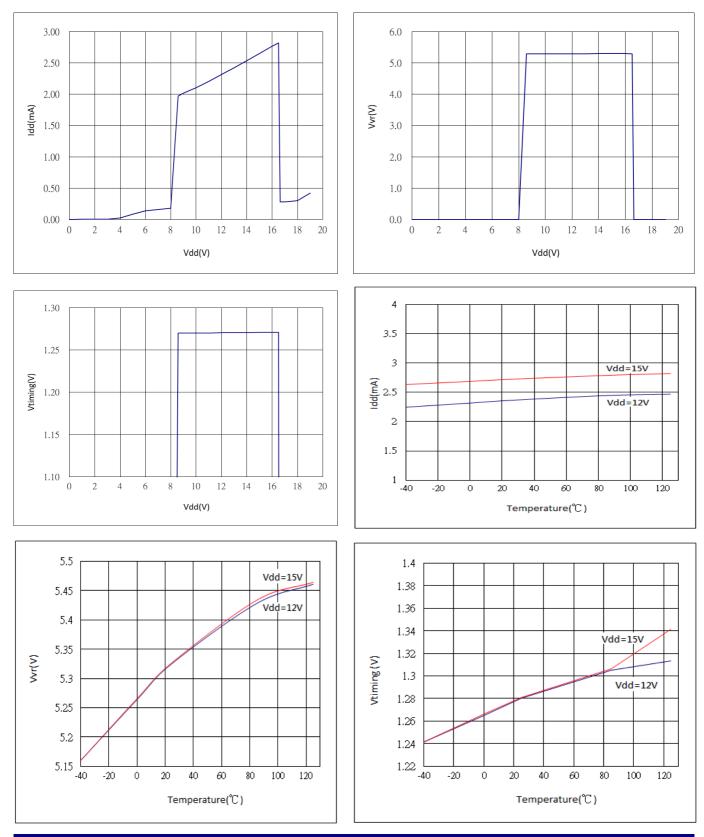
		outy Cycle=50%, unless otherwise spe		T		T T •4
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
SUPPLY IN	PUT					
IDD	Supply current	Sleep mode		0.25		mA
		V _{SYNC} =Vdd , Normal mode	1.8	2.3	3.0	mA
Vdd	Supply voltage	Idd peak < 2A			16	V
Vdd on	Enable voltage		8.0	8.5	9.0	V
Vdd hysteresis	Enable voltage		0.05	0.30	0.6	V
Vovp	Over voltage protection		16	16.5	17	V
Vovp hystersis			0.1	0.35	0.6	v
	ERENCE (SYNC)					
Vshth	SYNC high threshold			3.2		V
Vslth	SYNC low threshold			0.17		V
Vsync	SYNC wake-up voltage	Isync=3mA		10		V
Vsync	SYNC clamp voltage	Isync=3mA	Vdd+1.5			V
Isync	SYNC input current				3	mA
Voltage Reg	ulator REFERENCE (VF	<u></u> ,				
VR	voltage		5.2		5.4	V
Ivr	VR Output Current				50	mA
ON TIME D	UTY SETUP (PIN 6)	1				
Ton-time		Frequency= 10KHz-20KHz, Duty=20%~50%		26	32	uS
MOSFET G	ATE DRIVER (MOSG-C)				
Voh	Output high voltage	Io=-200mA	10.4	11.0		V
Vol	Output low voltage	Io=200mA		0.5	0.8	V
Td	Propagation delay	No load	220	275	350	nS
Tpred		Pin2 open		120		nS
Tr	Rise time	Load = 1nF(*)		10	25	nS
Tf	Fall time	Load = 1nF(*)		10	25	nS
Dynamic Pr	otect	· · · ·	1 1			
Dt	Dynamic variable	Pin 4 , 25KΩ		500		nS
Ton-min	MOSG-C on time	PWM adjusts time > Dt	0.45	0.6	0.85	uS



2018/1/26 Ver 1



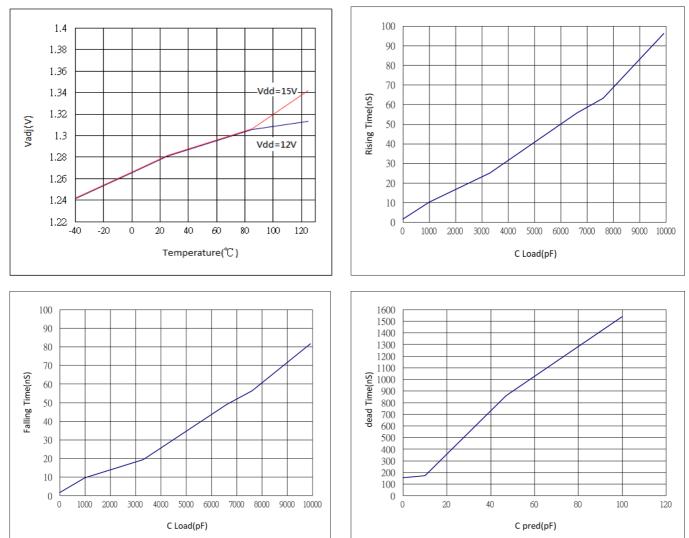
PERFORMANCE CHARACTERISTICS (T_A=25°C, unless otherwise specified.)



2018/1/26 Ver 1

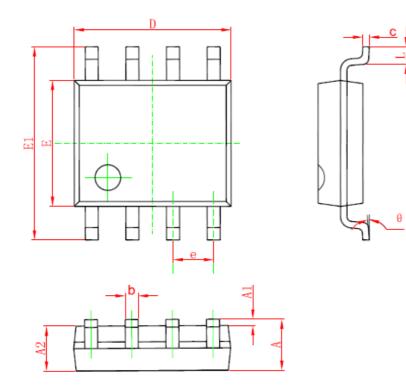


PERFORMANCE CHARACTERISTICS (T_A=25°C, unless otherwise specified.)





SOP- 8 PACKAGE OUTLINE



	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min	Max	Min	Max
A	1.350	1. 750	0.053	0.069
A1	0. 100	0. 250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0. 330	0.510	0.013	0.020
с	0. 170	0. 250	0.006	0.010
D	4. 700	5. 100	0. 185	0.200
E	3.800	4.000	0.150	0. 157
E1	5.800	6. 200	0. 228	0. 244
е	1. 270 (BSC)		0.050 (BSC)	
L	0. 400	1. 270	0.016	0.050
θ	0°	8°	0°	8°



Information provided is alleged to be exact and consistent. SYNC Power Corporation presumes no responsibility for the penalties of use of such information or for any violation of patents or other rights of third parties, which may result from its use. No license is granted by allegation or otherwise under any patent or patent rights of SYNC Power Corporation. Conditions mentioned in this publication are subject to change without notice. This publication surpasses and replaces all information previously supplied. SYNC Power Corporation products are not authorized for use as critical components in life support devices or systems without express written approval of SYNC Power Corporation.

 The SYNC Power logo is a registered trademark of SYNC Power Corporation
2018 SYNC Power Corporation – Printed in Taiwan – All Rights Reserved SYNC Power Corporation 7F-2, No.3-1, Park Street
NanKang District (NKSP), Taipei, Taiwan, 115, R.O.C Phone: 886-2-2655-8178 Fax: 886-2-2655-8468 http://www.syncpower.com